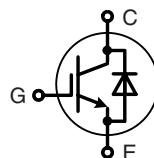


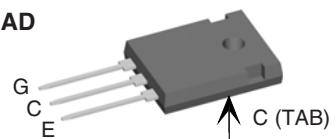
High Voltage BIMOSFET™ Monolithic Bipolar MOS Transistor

N-Channel, Enhancement Mode

I_{C25} = 33 A
 V_{CES} = 1600 V
 $V_{CE(sat)}$ = 6.2 V typ.
 t_{fi} = 40 ns



TO-247 AD



G = Gate,
E = Emitter, C = Collector,
TAB = Collector

Symbol	Conditions	Maximum Ratings			Features
V_{CES}	$T_J = 25^\circ\text{C}$ to 150°C	1600	V		• International standard package JEDEC TO-247 AD
V_{CGR}	$T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1 \text{ M}\Omega$	1600	V		• High Voltage BIMOSFET™ - replaces high voltage Darolithons and series connected MOSFETs - lower effective $R_{DS(on)}$
V_{GES}	Continuous	± 20	V		• Monolithic construction - high blocking voltage capability - very fast turn-off characteristics
V_{GEM}	Transient	± 30	V		• MOS Gate turn-on - drive simplicity
I_{C25}	$T_c = 25^\circ\text{C}$	33	A		• Intrinsic diode
I_{C90}	$T_c = 90^\circ\text{C}$	20	A		
I_{CM}	$T_c = 25^\circ\text{C}$, 1 ms	40	A		
SSOA (RBSOA)	$V_{GE} = 15 \text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 22 \Omega$, $V_{CE} = 0.8 \cdot V_{CES}$ Clamped inductive load, $L = 100 \mu\text{H}$	$I_{CM} = 40$	A		
P_c	$T_c = 25^\circ\text{C}$	350	W		
T_J		-55 ... +150	$^\circ\text{C}$		
T_{JM}		150	$^\circ\text{C}$		
T_{stg}		-55 ... +150	$^\circ\text{C}$		
T_L	1.6 mm (0.063 in) from case for 10 s	300	$^\circ\text{C}$		
M_d	Mounting torque	$1.15/10 \text{ Nm/lb.in.}$			
Weight		6	g		

Symbol	Conditions	Characteristic Values			Applications
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.	
BV_{CES}	$I_C = 1 \text{ mA}$, $V_{GE} = 0 \text{ V}$	1600			• AC motor speed control
$V_{GE(th)}$	$I_C = 2 \text{ mA}$, $V_{CE} = V_{GE}$	4		8	DC servo and robot drives
I_{CES}	$V_{CE} = 0.8 \cdot V_{CES}$ $V_{GE} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		400 μA 3 mA	DC choppers
I_{GES}	$V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$			± 500 nA	Uninterruptible power supplies (UPS)
$V_{CE(sat)}$	$I_C = I_{C90}$, $V_{GE} = 15 \text{ V}$	$T_J = 125^\circ\text{C}$	6.2	7.1 7.8	Switched-mode and resonant-mode power supplies

IXYS reserves the right to change limits, test conditions and dimensions.

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Symbol	Conditions	Characteristic Values			
		($T_J = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.	max.
C_{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	3300		pF	
C_{oes}		220		pF	
C_{res}		30		pF	
Q_g	$I_C = 20 \text{ A}, V_{CE} = 600 \text{ V}, V_{GE} = 15 \text{ V}$	130		nC	
$t_{d(on)}$	Inductive load, $T_J = 125^\circ\text{C}$	200		ns	
t_{ri}		60		ns	
$t_{d(off)}$		270		ns	
t_{fi}		40		ns	
R_{thJC}			0.25	0.35	K/W
R_{thCK}					K/W

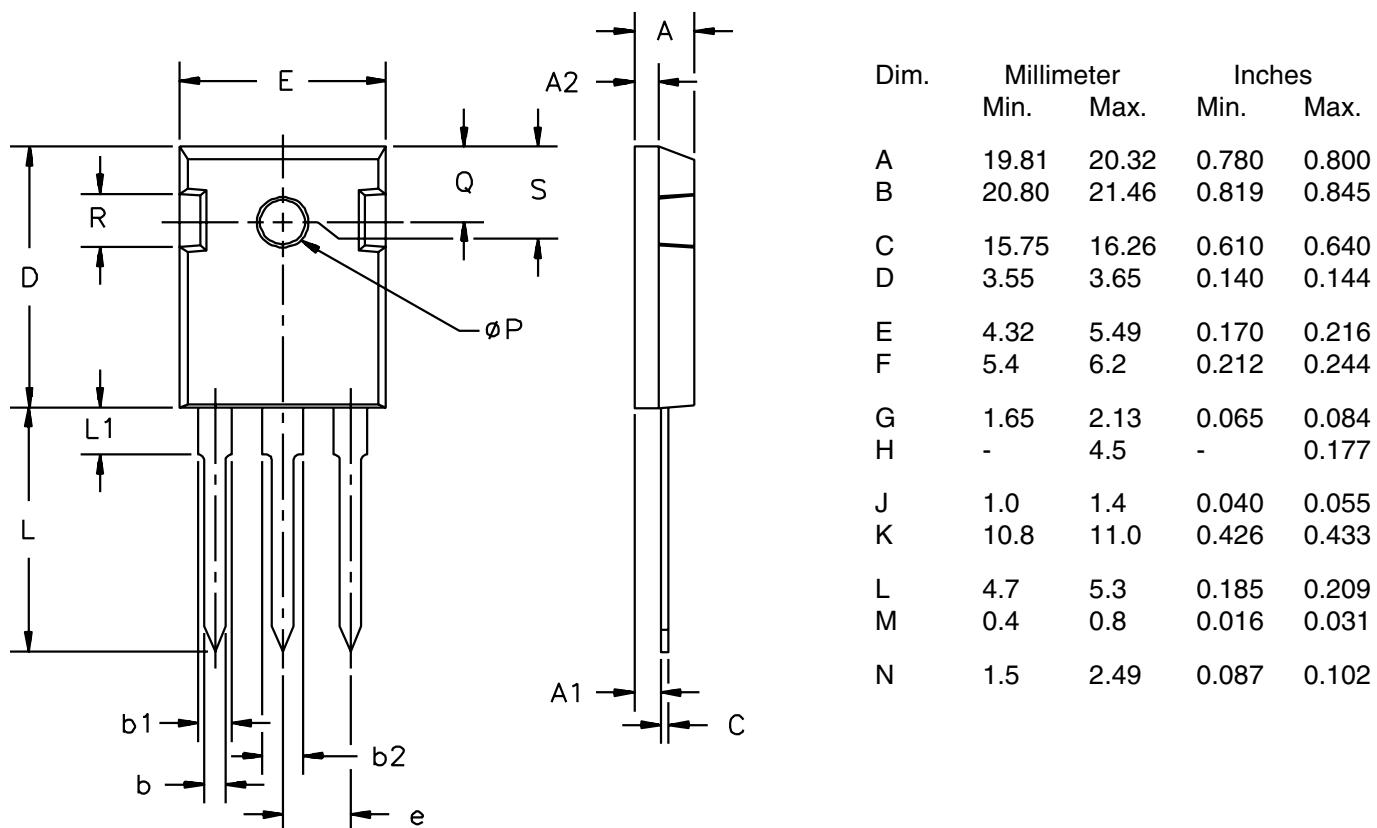
Reverse Conduction

Characteristic Values

 $(T_J = 25^\circ\text{C}, \text{unless otherwise specified})$

Symbol	Conditions	min.	typ.	max.
V_F	$I_F = I_{C90}, V_{GE} = 0 \text{ V}, \text{Pulse test}$ $t \leq 300 \mu\text{s}, \text{duty cycle } d \leq 2\%$	2.5	5	V

TO-247 AD Outline



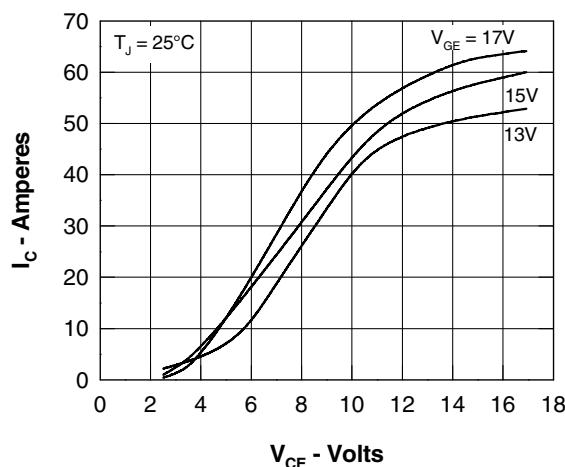


Fig. 1 Typ. Output Characteristics

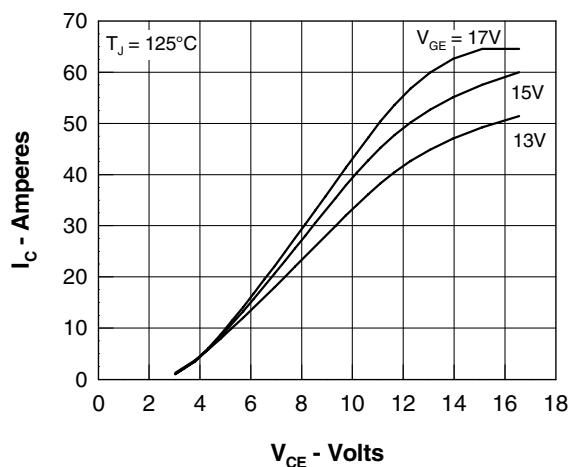


Fig. 2 Typ. Output Characteristics

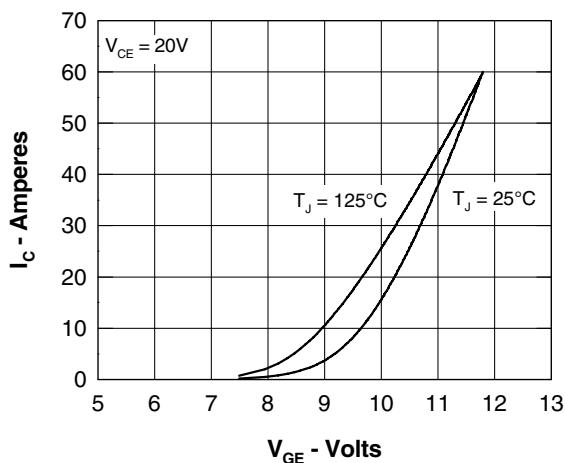


Fig. 3 Typ. Transfer Characteristics

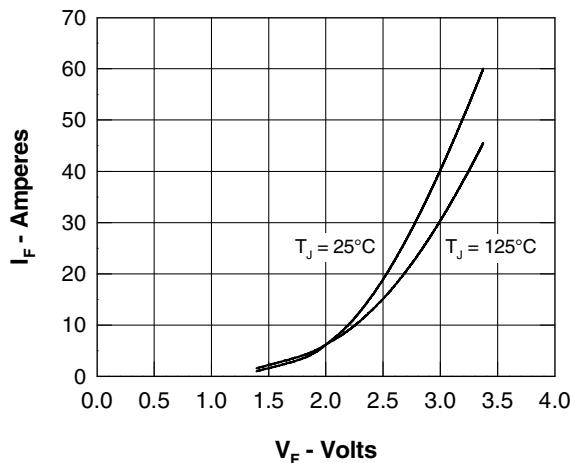


Fig. 4 Typ. Characteristics of Reverse Conduction

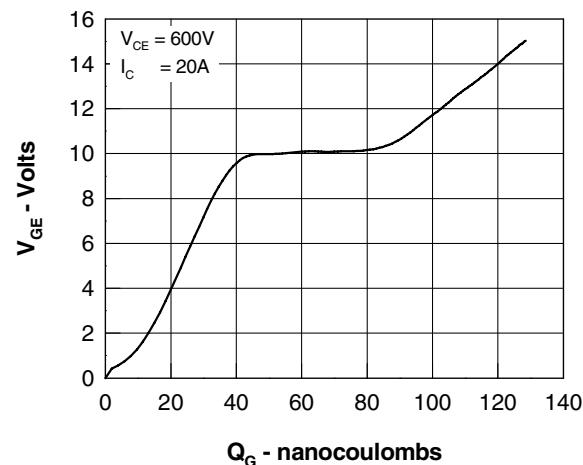


Fig. 5 Typ. Gate Charge characteristics

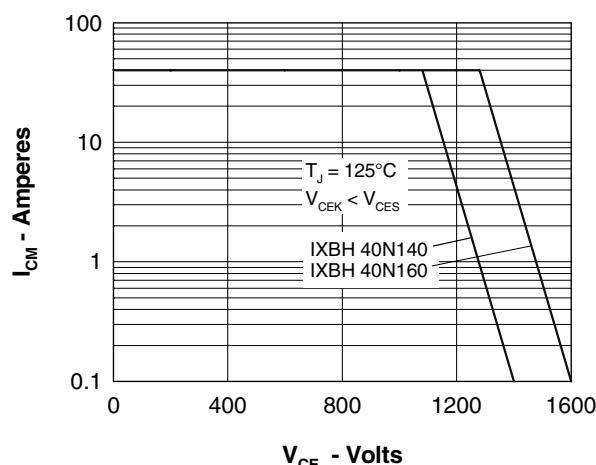


Fig. 6 Reverse Based Safe Operating Area RBSOA

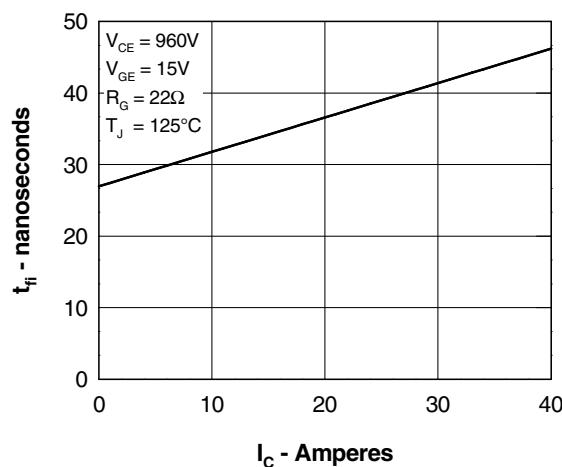


Fig. 7 Typ. Fall Time

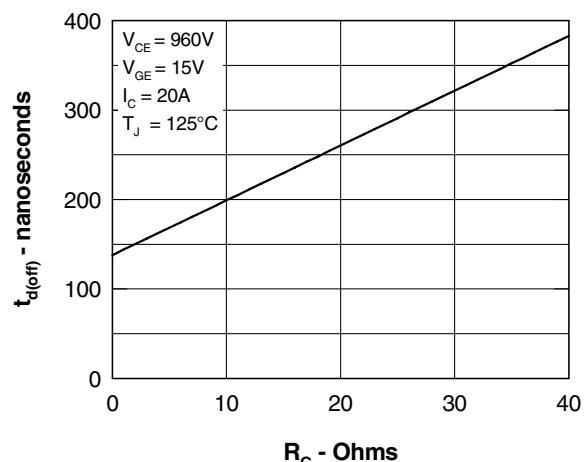


Fig. 8 Typ. Turn Off Delay Time

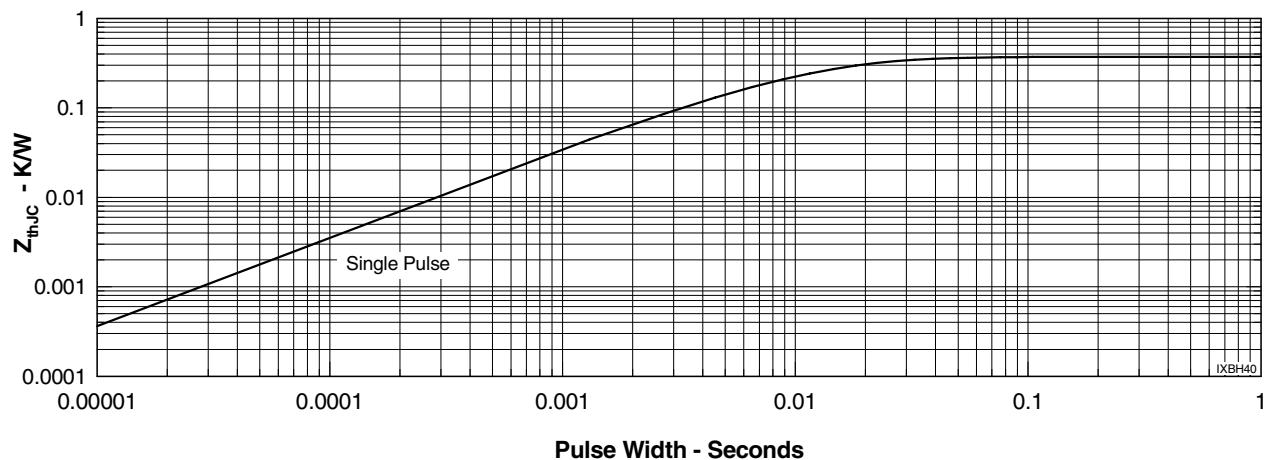


Fig. 9 Typ. Transient Thermal Impedance

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[XD25H120CX0](#) [XP15PJS120CL1B1](#) [IGW30N60H3FKSA1](#) [STGWA8M120DF3](#) [IGW08T120FKSA1](#) [IGW75N60H3FKSA1](#)
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[IKP20N60TXKSA1](#) [IHW20N65R5XKSA1](#)